

**INSTITUTE OF AERONAUTICAL ENGINEERING**

(Autonomous)

B.TECH II Semester End Examinations (Regular) AUGUST- 2021

Regulation:UG20

**APPLIED PHYSICS****Time: 3 Hours**

(CSE|IT|CSE(AIML)|CSE(CS)|CSE(DS)|CSIT)

**Max Marks: 70****Answer all questions in Modules I and II****Answer ONE out of two questions from Modules III, IV and V**

(NOTE: Provision is given to answer TWO questions from among one of the Modules III / IV / V)

**All Questions Carry Equal Marks****All parts of the question must be answered in one place only****MODULE – I**

1. (a) Describe an experimental technique which is direct proof that particles like electrons are associated waves when they are in motion. [7M]
- (b) Find the De Broglie wavelength of an electron whose speed is  $2.0 \times 10^8$  m/sec. [7M]

**MODULE – II**

2. (a) Discuss the motion of an electron in a periodic potential. Explain how the above theory leads to the concept of band structure of solids. [7M]
- (b) The intrinsic carrier density at room temperature in Ge is  $2.37 \times 10^{19}$  /m<sup>3</sup>. If the electron and hole mobilities are 0.38 and 0.18 m<sup>2</sup>/V sec respectively. Calculate the resistivity. [7M]

**MODULE – III**

3. (a) Explain in detail direct and indirect band gap semiconductors with energy band diagrams and examples. [7M]
- (b) Calculate the forward bias current of a Si diode when forward bias voltage of 0.4V is applied, the reverse saturation current is  $1.17 \times 10^{-9}$  A and the thermal voltage is 25.2mV. [7M]
4. (a) Explain the construction and working of solar cell with suitable diagrams. Draw the V-I characteristics of solar cell. [7M]
- (b) Consider a silicon diode with  $\eta=1.2$ . Find the change in voltage if the current changes from 0.1mA to 10mA. [7M]

**MODULE – IV**

5. (a) Give a schematic sketch of different types of polarization and explain in detail. [7M]
- (b) Consider a parallel plate capacitor having an area  $6.45 \times 10^{-4}$  m<sup>2</sup> and a plate separation of  $2 \times 10^{-3}$  m across which a potential of 10 V is applied. If a material having dielectric constant of 6.0 is positioned with in the region between the plates. Compute  
i) The capacitance ii) Magnitude of the charge stored on each plate. [7M]
6. (a) List the differences between diamagnetic, paramagnetic, and ferromagnetic materials. [7M]

- (b) The magnetic flux density within a bar of some material is 0.63 Tesla at an H field of  $5 \times 10^5$  A/m. Compute i) The magnetic susceptibility ii) Magnetic permeability. [7M]

**MODULE – V**

7. (a) Explain the principle of operation of optical fiber. Draw a schematic layout of a step index optical fiber. [7M]
- (b) A step index fiber has a core of refractive index 1.5. If the numerical aperture of the fiber is 0.26, calculate the refractive index of the cladding material. [7M]
8. (a) Explain the construction and working of a ruby laser system with suitable energy level diagram. [7M]
- (b) In a material, transition occurs between a metastable state and an energy level of 0.25 eV. The wavelength of the radiation emitted is 1100nm. Calculate the energy of the metastable state. [7M]

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